NSN 5962-01-253-0176

Memory Microcircuit - Page 1 of 2



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Body Length:	
1.290 inches	
Body Width:	
0.610 inches	
Body Height:	
0.150 inches	
Maximum Power Dissipation Rating:	
1.0 watts	
Operating Tempurature Range:	
55.0/+125.0 degrees celsius	
Storage Tempurature Range:	
65.0/+150.0 degrees celsius	
End Application:	
Radar set an/sps-4 (v) 5	
Features Provided:	
Schottky and programmable and bipolar	
nclosure Material:	
Ceramic	
Inclosure Configuration:	
Dual-in-line	
Dutput Logic Form:	
Fransistor-transistor logic	
nput Circuit Pattern:	
14 input	
Case Outline Source And Designator:	
D-3 mil-m-38510	
Terminal Surface Treatment:	
Solder	
/oltage Rating And Type Per Characte	eristic:
7.0 volts power source	
Time Rating Per Chacteristic:	
100.00 nanoseconds propagation delay	time, low to high level output and 100.00 nanoseconds propagation delay time, high to low level
output	
Memory Device Type:	
Rom	
Memory Capacity:	
Unknown	
Test Data Document:	
96906-mil-std-883 standard (includes ind	lustry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:	
24 printed circuit	
Shelf Life:	
N1/	

NSN 5962-01-253-0176

Memory Microcircuit - Page 2 of 2

Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

A458a0

